

Two-Terminal IC 1.2 V Reference

AD589

FEATURES

Superior Replacement for Other 1.2 V References Wide Operating Range: 50 μ A to 5 mA Low Power: 60 μ W Total P_D at 50 μ A

Low Temperature Coefficient:

10 ppm/°C max, 0°C to +70°C (AD589M) 25 ppm/°C max, -55°C to +125°C (AD589U)

Two-Terminal "Zener" Operation Low Output Impedance: 0.6 Ω

No Frequency Compensation Required

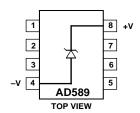
Low Cost

MIL-STD-883 Compliant Versions Available

FUNCTIONAL BLOCK DIAGRAMS

SOIC (SO-8)

Metal Can (H-02A)





PRODUCT DESCRIPTION

The AD589 is a two-terminal, low cost, temperature compensated bandgap voltage reference which provides a fixed 1.23 V output voltage for input currents between 50 μ A and 5.0 mA.

The high stability of the AD589 is primarily dependent upon the matching and thermal tracking of the on-chip components. Analog Devices' precision bipolar processing and thin-film technology combine to provide excellent performance at low cost.

Additionally, the active circuit produces an output impedance ten times lower than typical low-TC Zener diodes. This feature allows operation with no external components required to maintain full accuracy under changing load conditions.

The AD589 is available in seven versions. The AD589J, K, L and M grades are specified for 0° C to $+70^{\circ}$ C operation, while the S, T, and U grades are rated for the full -55° C to $+125^{\circ}$ C temperature range. All grades are available in a metal can (H-02A) package. The AD589J is also available in an 8-pin SOIC package.

PRODUCT HIGHLIGHTS

- The AD589 is a two-terminal device which delivers a constant reference voltage for a wide range of input current.
- 2. Output impedance of $0.6~\Omega$ and temperature coefficients as low as 10 ppm/°C insure stable output voltage over a wide range of operating conditions.
- 3. The AD589 can be operated as a positive or negative reference. "Floating" operation is also possible.
- 4. The AD589 will operate with total current as low as $50 \,\mu\text{A}$ (60 μW total power dissipation), ideal for battery powered instrument applications.
- 5. The AD589 is an exact replacement for other 1.2 V references, offering superior temperature performance and reduced sensitivity to capacitive loading.
- 6. The AD589 is available in versions compliant with MIL-STD-883. Refer to the Analog Devices Military Products Databook or current AD589/883B data sheet for detailed specifications.

$AD589 - SPECIFICATIONS \text{ (typical @ I_{IN} = 500 } \mu\text{A and } T_A = +25^{\circ}\text{C unless otherwise noted)}$

Model	AD589JH/JR			AD589KH			AD589LH			AD589MH			
	Min	Тур	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Unit
OUTPUT VOLTAGE, $T_A = +25$ °C	1.200	1.235	1.250	1.200	1.235	1.250	1.200	1.235	1.250	1.200	1.235	1.250	V
OUTPUT VOLTAGE CHANGE vs. CURRENT			_			-			_			_	
(50 μA-5 mA)			5			5			5			5	mV
DYNAMIC OUTPUT IMPEDANCE		0.6	2		0.6	2		0.6	2		0.6	2	Ω
RMS NOISE VOLTAGE 10 Hz < f < 10 kHz		5			5			5			5		μV
TEMPERATURE COEFFICIENT ¹			100			50			25			10	ppm/°C
TURN-ON SETTLING TIME TO 0.1%		25			25			25			25		μs
OPERATING CURRENT ²	0.05		5	0.05		5	0.05		5	0.05		5	mA
OPERATING TEMPERATURE	0		+70	0		+70	0		+70	0		+70	°C
PACKAGE OPTION ³ Metal Can (H-02A) SOIC (R-8)	AD589JH AD589JR		AD589KH		AD589LH		AD589MH						

Model	AD589SH			AD589TH			AD589UH			
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Unit
OUTPUT VOLTAGE, $T_A = +25^{\circ}C$	1.200	1.235	1.250	1.200	1.235	1.250	1.200	1.235	1.250	V
OUTPUT VOLTAGE CHANGE vs. CURRENT										
(50 μA-5 mA)			5			5			5	mV
DYNAMIC OUTPUT IMPEDANCE		0.6	2		0.6	2		0.6	2	Ω
RMS NOISE VOLTAGE 10 Hz < f < 10 kHz		5			5			5		μV
TEMPERATURE COEFFICIENT ¹			100			50			25	ppm/°C
TURN-ON SETTLING TIME TO 0.1%		25			25			25		μs
OPERATING CURRENT ²	0.05		5	0.05		5	0.05		5	mA
OPERATING TEMPERATURE	-55		+125	-55		+125	-25		+125	°C
PACKAGE OPTION ³ Metal Can (H-02A) SOIC (SO-8)	AD589SH AD589JR		AD589TH		AD589UH					

NOTES

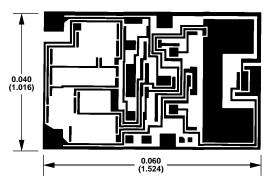
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ABSOLUTE MAXIMUM RATINGS

Current
Reverse Current
Power Dissipation ¹ 125 mW
Storage Temperature65°C to +175°C
Operating Junction Temperature Range55°C to +150°C
Lead Temperature (Soldering, 10 sec) +300°C
NOTE

 1Absolute maximum power dissipation is limited by maximum current through the device. Maximum rating at elevated temperatures must be computed assuming $T_J \leq 150^{\circ}C,$ and $\theta_{JA} = 400 = C/W.$

AD589 CHIP DIMENSIONS AND PAD LAYOUT



THE AD589 IS AVAILABLE IN CHIP FORM WITH FULLY TESTED AND GUARANTEED SPECIFICATIONS. CONSULT FACTORY FOR AVAILABLE GRADES AND PRICING.

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 $^{^1\!\}mathrm{See}$ the following page for explanation of temperature coefficient measurement method.

²Optimum performance is obtained at currents below 500 μ A. For current operation below 200 μ A, stray shunt capacitances should be limited to 20 pF or increased to 1 μ F. If strays can not be avoided, operation at 500 μ A and a shunt capacitor of at least 1000 pF are recommended. ³H = Hermetic Metal Can; SO = SOIC.

 $Specifications \ shown \ in \ \textbf{boldface} \ \ are \ tested \ on \ all \ production \ units \ at \ final \ electrical \ test.$

Specifications subject to change without notice.

Understanding the Specifications–AD589

VOLTAGE VARIATION VS. TEMPERATURE

Some confusion exists in the area of defining and specifying reference voltage error over temperature. Historically, references have been characterized using a maximum deviation per degree Centigrade; i.e., 10 ppm/°C. However, because of nonlinearities in temperature characteristics, which originated in standard Zener references (such as "S" type characteristics) most manufacturers have begun to use a maximum limit error band approach to specify devices. This technique involves measurement of the output at 3, 5 or more different temperatures to guarantee that the output voltage will fall within the given error band. The temperature characteristics of the AD589 consistently follows the curve shown in Figure 1. Three-point measurement guarantees the error band over the specified temperature range. The temperature coefficients specified on the previous page represent the slopes of the diagonals of the error band from $+25^{\circ}$ C to T_{MIN} and $+25^{\circ}$ C to T_{MAX} .

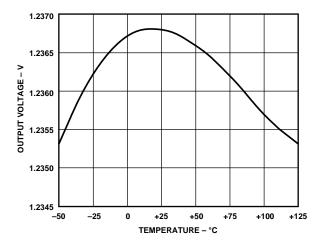


Figure 1. Typical AD589 Temperature Characteristics

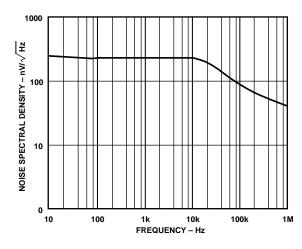


Figure 2. Noise Spectral Density

DYNAMIC PERFORMANCE

Many low power instrument manufacturers are becoming increasingly concerned with the turn-on characteristics of the components being used in their systems. Fast turn-on components often enable the end user to keep power off when not needed, and yet respond quickly when the power is turned on for operation. Figure 3 displays the turn-on characteristics of the AD589. This characteristic is generated from cold-start operation and represents the true turn-on waveform after an extended period with the supplies off. The figure shows both the coarse and fine transient characteristics of the device; the total settling time to within ± 1 millivolt is about 25 μs , and there is no long thermal tail appearing after that point.

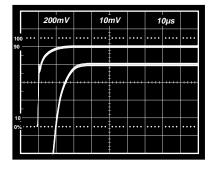


Figure 3. Output Settling Characteristics

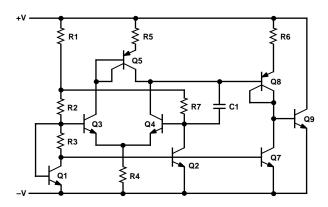


Figure 4. Schematic Diagram

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AD589

APPLICATION INFORMATION

The AD589 functions as a two-terminal shunt-type regulator. It provides a constant 1.23 V output for a wide range of input current from 50 μA to 5 mA. Figure 5 shows the simplest configuration for an output voltage of 1.2 V or less. Note that no frequency compensation is required. If additional filtering is desired for ultralow noise applications, minimum recommended capacitance is 1000 pF.

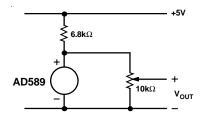


Figure 5. Basic Configuration for 1.2 V or Less

The AD589 can also be used as a building block to generate other values of reference voltage. Figure 6 shows a circuit which produces a buffered 10 V output. Total supply current for this circuit is approximately 2 mA.

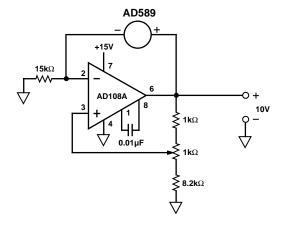
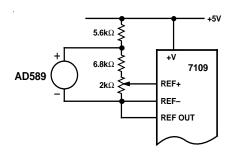
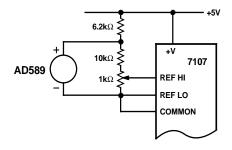


Figure 6. Single Supply Buffered 10 V Reference

The low power operation of the AD589 makes it ideal for use in battery operated portable equipment. It is especially useful as a reference for CMOS analog-to-digital converters. Figure 7 shows the AD589 used in conjunction with two popular integrating type CMOS A/D converters.



a. With 7109 12-Bit Binary A/D



b. With 7107 Panel Meter A/D

Figure 7. AD589 Used as Reference for CMOS A/D Converters

The AD589 also is useful as a reference for CMOS multiplying DACs such as the AD7533. These DACs require a negative reference voltage in order to provide a positive output range. Figure 8 shows the AD589 used to supply an equivalent –1.0 V reference to an AD7533.

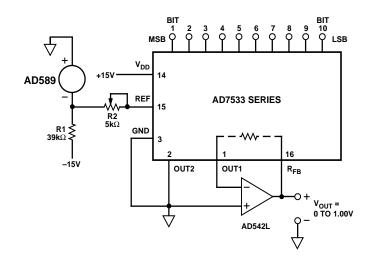
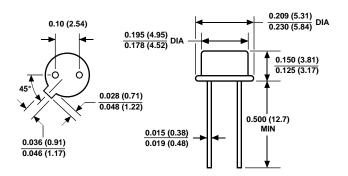


Figure 8. AD589 as Reference for 10-Bit CMOS DAC

OUTLINE DIMENSIONS AND PIN DESIGNATIONS

Dimensions shown in inches and (mm).



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Package/Price Information

For detailed packaging information, please select the Datasheets button.

Two-Terminal IC 1.2 V Reference

Model	Status	Package Description	Pin Count	Temperature Range	Price* (100- 499)
AD589JCHIPS	PRODUCTION	CHIPS/DIE SALES	2	COMMERCIAL	\$1.39
AD589JH	PRODUCTION	ROUND HEADER/METAL CAN	3	COMMERCIAL	\$4.02
AD589JH/+	OBSOLETE	ROUND HEADER/METAL CAN	3	COMMERCIAL	-
AD589JR	PRODUCTION	STD S.O. PKG (SOIC)	8	COMMERCIAL	\$1.72
AD589JR- REEL	PRODUCTION	STD S.O. PKG (SOIC)	8	COMMERCIAL	-
AD589KH	PRODUCTION	ROUND HEADER/METAL CAN	2	COMMERCIAL	\$4.35
AD589LH	PRODUCTION	ROUND HEADER/METAL CAN	3	COMMERCIAL	\$8.89
AD589MH	PRODUCTION	ROUND HEADER/METAL CAN	3	COMMERCIAL	\$19.32
AD589SH	PRODUCTION	ROUND HEADER/METAL CAN	3	MILITARY	\$4.76
AD589SH/883B	PRODUCTION	ROUND HEADER/METAL CAN	3	MILITARY	\$10.02
AD589TCHIPS	PRODUCTION	CHIPS/DIE SALES	2	MILITARY	\$4.48
AD589TH	PRODUCTION	ROUND HEADER/METAL CAN	3	MILITARY	\$6.92
AD589TH/883B	PRODUCTION	ROUND HEADER/METAL CAN	3	MILITARY	\$13.55

^{*} This price is provided for budgetary purposes as recommended list price in U.S. Dollars per unit the stated volume. Pricing displayed for Evaluation Boards and Kits is based on 1-piece pricing. View Pricing and Availability (currently available to North American customers) for further information.